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## ABSTRACT OF THE DISCLOSURE

A laser apparatus includes a semiconductor laser element having a first active layer made of a GaN-based emitting first laser light; and surface-emitting semiconductor element having a second layer made of a GaN-based compound, being active excited with the first laser light, and emitting second laser light. Ιn addition, the surface-emitting semiconductor element may have a first mirror arranged on one side of the second active layer, and a second arranged outside the surface-emitting may be semiconductor element so that the first and mirrors form a resonator.